

SZMD03C

24W, 3 V Transient Voltage Suppressors for ESD Protection (Uni-directional)

RoHS Compliant Product A suffix of "-C" specifies halogen & lead-free

FEATURES

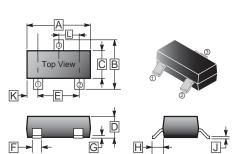
- SOT-23 package for surface mount application
- Protects 5V components
- Protects two unidirectional line or one bi-direction line
- Provides electrically is olated protection

APPLICATIONS

- Cellular Handsets and Accessories
- Portable devices
- Industrial Controls
- Set -Top Box
- Servers, Notebook, and Desktop PC

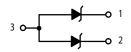
Marking Code

KD9



SOT-23

REF.	Millimeter		REF.	Millimeter	
	Min.	Max.	NLF.	Min.	Max.
А	2.80	3.00	G	0.10 REF.	
В	2.25	2.55	Н	0.55 REF.	
С	1.20	1.40	J	0.08	0.15
D	0.90	1.15	K	0.5 REF.	
E	1.80	2.00	L	0.95 TYP.	
F	0.30	0.50			



ABSOLUTE RATINGS (Tamb = 25°C)

R	Symbol	Value	Units	
IEC 61000-4-2 (ESD)	Air contact		±15	kV
	Contact discharge		±8	kV
ESD voltage	Per human body model		16	kV
Total power dissipation on FR-5	PD	150	m/W	
Junction and storage temperatu	T _J , T _{STG}	-55 ~ +150	°C	
Lead solder temperature - max	TL	260	°C	

Stresses exceeding Maximum Ratings may damage the device. Maximum Rating are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability. 1. FR-5 = 1.0*0.75*0.62 in.

ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified. $V_F = 0.9V$ at $I_F = 10$ mA)

Device	V _{RWM} (V)	I _R (uA) @ V _{RWM}	V _{BR} (V) @ I _T (Note 2)	Ι _τ (mA)	V _C (V) @ Max I _{PP} (Note 3)	I _{PP} (A) (Note 3)	Р _{РК} (W)*	C (pF) (Note 4)
	Max	Max	Min	mA	Max	Max	Max	Тур
SZMD03C	3	5.0	5.2	5.0	8.0	3.0	24	190

Other voltages available upon request.

2. V_{BR} is measured with a pulse test current I_T at an ambient temperature of $25^\circ\!{\rm C}$

3. Surge current waveform per Figure 3.

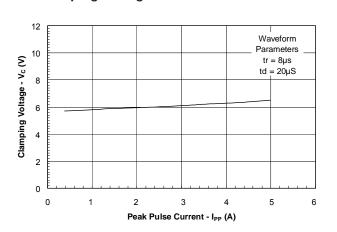
4. Measured at 1MHz 0V.



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RATINGS AND CHARACTERISTICS CURVES



Clamping Voltage vs. Peak Pulse Current

Pulse Waveform 110 Wave form 100 Paramete rs: 90 tr=8 s td = 20 s 80 £ 70 e⁻¹ Percent of I 60 50 40 30 20 10 0 5 15 10 20 25 30 0 Time (us)

Power Derating Curve 110 100 Ч 90 % of Rated Power or I 80 70 60 50 40 30 20 10 0 0 25 50 75 100 125 150 Ambient Temperature - T_A (^oC)

Applications Information

Device Connection Options

The SZMD series is designed to protect one bi-directional or two uni-directional data or I/O lines operating at 3 volts.Connection options are as follows:

• Bidirectional:Pin 1 is connected to the data line and pin 2 is connected to ground (Since the device IIs symmetrical,these conmtions may be re- Ver3ed).For best results,the ground connection should be made directly to a ground plane on the board.The path length should be kept as short as possible to minimize parasitic inductance-Pin 3 is not

connected. • Unidirectional:Data lines are connected to pin1 and pin2.Pin 3 is connected to ground.For best results, this pin should be connected directly to a ground plane on the board. The path lengh should be kept as short as possible to minimize parasitic inductance. Circuit Board Layout Recommendations for suppres- sion of ESD. Good circuit board layout is critical for the suppression of fast rise-time transients such as ESD. The following guidelines are recommended (Refer to application note SI99.01 for more detailed information): • Place the TVS near the input terminals or connec- tors to restrict transient coupling. • Minimize the path length between the TVS and the protected line. • Minimize all conductive loops including power and ground loops. • The ESD transient return path toground should be kept as short as possible. • Never run critical signals near board edaes

• Use ground planes whenever possible.

http://www.SeCoSGmbH.com/